# 2N2221 2N2222

# SILICON NPN TRANSISTORS



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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N2221 and 2N2222 are silicon NPN epitaxial planar transistors designed for small signal, general purpose switching applications.

MARKING: FULL PART NUMBER



I<sub>C</sub>=150mA, I<sub>B</sub>=15mA

 $I_C$ =500mA,  $I_B$ =50mA

V<sub>CE</sub>=20V, I<sub>C</sub>=20mA, f=100MHz

 $V_{CB}$ =10V,  $I_E$ =0, f=100kHz

 $V_{EB}$ =0.5V,  $I_{C}$ =0, f=100kHz

V<sub>BE</sub>(SAT)

V<sub>BE</sub>(SAT)

 $f_T$ 

 $C_{\mathsf{ob}}$ 

 $C_{ib}$ 

MAXIMUM R	ATINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Collector-Base Voltage		$V_{CBO}$	60	V
Collector-Emitter Voltage		$V_{CEO}$	30	V
Emitter-Base Voltage		V <sub>EBO</sub>	5.0	V
Continuous C	Collector Current	lc	800	mA
Power Dissip	ation	$P_{D}$	500	mW
Power Dissip	ation (T <sub>C</sub> =25°C)	P <sub>D</sub>	1.2	W
Operating an	d Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200	°C
Thermal Resi	istance	$\Theta_{JA}$	350	°C/W
Thermal Resistance		$\Theta$ JC	146	°C/W
ELECTRICA	L CHARACTERISTICS: (T <sub>A</sub> =25°C t	unless otherwise no	oted)	
SYMBOL	TEST CONDITIONS `	MIN	MAX	UNITS
ICBO	V <sub>CB</sub> =50V	-	10	nA
I <sub>CBO</sub>	V <sub>CB</sub> =50V, T <sub>A</sub> =150°C	-	10	μΑ
I <sub>EBO</sub>	V <sub>EB</sub> =3.0V	-	10	nA
$BV_{CBO}$	I <sub>C</sub> =10μA	60	-	V
$BV_{CEO}$	I <sub>C</sub> =10mA	30	-	V
$BV_{EBO}$	I <sub>E</sub> =10μA	5.0	-	V
V <sub>CE</sub> (SAT)	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA	-	0.4	V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA	-	1.6	V
	I 450 A I 45 A	0.0	4.0	

0.6

250

V

V

MHz

рF

рF

1.3

2.6

-

8.0

30

# 2N2221 2N2222

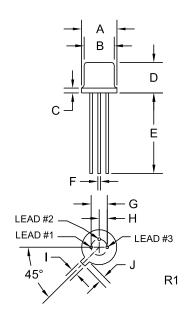
# SILICON NPN TRANSISTORS



# ELECTRICAL CHARACTERISTICS - Continued: (T<sub>A</sub>=25°C unless otherwise noted) 2N2221 2N2222

		<u>2N2221</u>		<u>2N2</u>	<u>2N2222</u>	
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =0.1mA	20	-	35	-	
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =1.0mA	25	-	50	-	
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	35	-	75	-	
h <sub>FE</sub>	$V_{CE}$ =10V, $I_{C}$ =10mA, $T_{A}$ =-55°C	15	-	35	-	
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =150mA	40	120	100	300	
hFE	V <sub>CE</sub> =1.0V, I <sub>C</sub> =150mA	20	-	50	-	
h <sub>FE</sub>	$V_{CE}$ =10V, $I_{C}$ =500mA	25	-	40	-	

# **TO-18 CASE - MECHANICAL OUTLINE**



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
A (DIA)	0.209	0.230	5.31	5.84			
B (DIA)	0.178	0.195	4.52	4.95			
С	-	0.030	-	0.76			
D	0.170	0.210	4.32	5.33			
E	0.500	-	12.70	-			
F (DIA)	0.016	0.019	0.41	0.48			
G (DIA)	0.100		2.54				
Н	0.050		1.27				
I	0.036	0.046	0.91	1.17			
J	0.028	0.048	0.71	1.22			
TO 40 (DEV/, D4)							

TO-18 (REV: R1)

# LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

R2 (24-July 2013)

### **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

### **CONTACT US**

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